

# UTC UNISONIC TECHNOLOGIES CO., LTD

BAV70W **DIODE** 

# **DUAL SURFACE MOUNT** SWITCHING DIODE

#### **DESCRIPTION**

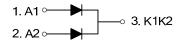
The UTC BAV70W is a dual surface mount switching diode providing the designers high switching speed, high conductance and high reliability.

The UTC **BAV70W** is suitable for common switching applications.

#### **FEATURES**

- \* High Switching Speed
- \* High Conductance
- \* High Reliability
- \* Green Product

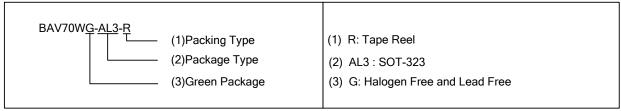
#### **SYMBOL**



#### ORDERING INFORMATION

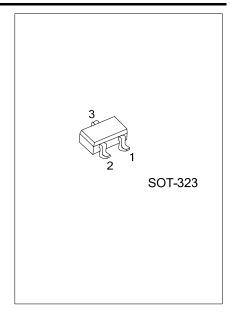
Ordering Number	Package	Pin Assignment			Doolsing	
		1	2	3	Packing	
BAV70WG-AL3-R	SOT-323	A1	A2	K1K2	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



#### **MARKING**





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# ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Non-Repetitive Reverse Voltage		$V_{RM}$	100	V	
Peak Repetitive Reverse Voltage		$V_{RRM}$	75	V	
Working Peak Reverse Voltage		$V_{RWM}$	75	V	
DC Blocking Voltage		$V_R$	75	V	
RMS Reverse Voltage		$V_{R(RMS)}$	53	V	
Forward Continuous Current		I <sub>FM</sub>	300	mA	
Average Rectified Output Current		l <sub>o</sub>	150	mA	
Non-Repetitive Peak Forward Surge	@ t = 1.0µs		2.0	Α	
Current	@ t = 1.0s	I <sub>FSM</sub>	1.0		
Power Dissipation		$P_{D}$	200	mW	
Operating Temperature		TJ	-65~+150	°C	
Storage Temperature		T <sub>STG</sub>	-65~+150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance Junction to Ambient Air	$\theta_{JA}$	625	°C/W

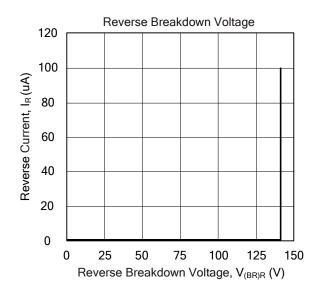
# ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C unless otherwise specified.)

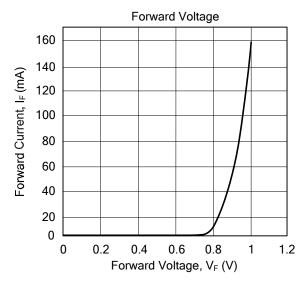
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Reverse Breakdown Voltage (Note)	$V_{(BR)R}$	I <sub>R</sub> = 100μA	75			V	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 1.0mA			0.715	V	
		I <sub>F</sub> = 10mA			0.855		
		I <sub>F</sub> = 50mA			1.0	V	
		I <sub>F</sub> = 150mA			1.25		
Reverse Current (Note 1)	I <sub>R</sub>	V <sub>R</sub> = 75V			2.5		
		V <sub>R</sub> = 75V, T <sub>J</sub> = 150°C			50	μΑ	
		V <sub>R</sub> = 25V, T <sub>J</sub> = 150°C			30		
		V <sub>R</sub> =20V			25	nA	
Total Capacitance	$C_T$	V <sub>R</sub> = 0, f = 1.0MHz			2.0	pF	
Reverse Recovery Time	t <sub>rr</sub>	$I_F$ = $I_R$ = 10mA, $I_{rr}$ = 0.1 x $I_R$ , $R_L$ = 100 $\Omega$			4.0	ns	

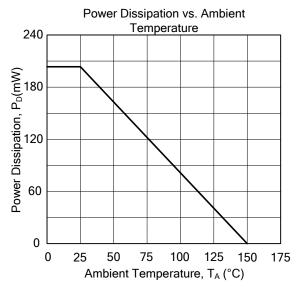
Notes: Short duration test pulse used to minimize self-heating effect.

BAV70W DIODE

#### ■ TYPICAL CHARACTERISTICS







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